
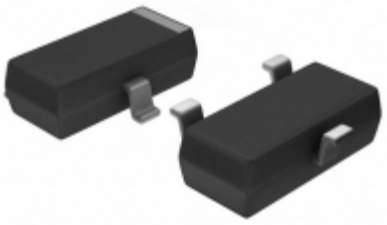
	<p>SI2374DS-T1-GE3</p>
	<p>Hersteller-Teilenummer: SI2374DS-T1-GE3</p> <p>Hersteller / Marke: Electro-Films (EFI) / Vishay</p> <p>Teil der Beschreibung: MOSFET N-CHAN 20V SOT23</p> <p>Datenblätter:  SI2374DS-T1-GE3.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 85238 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	SI2374DS-T1-GE3
Hersteller	Electro-Films (EFI) / Vishay
Beschreibung	MOSFET N-CHAN 20V SOT23
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	85238 pcs Stock
detaillierte Beschreibung	N-Channel 20V 4.5A (Ta), 5.9A (Tc) 960mW (Ta),
Serie	TrenchFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-236-3, SC-59, SOT-23-3
Supplier Device-Gehäuse	SOT-23-3 (TO-236)
Verlustleistung (max)	960mW (Ta), 1.7W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	20V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	4.5A (Ta), 5.9A (Tc)
Rds On (Max) @ Id, Vgs	30 mOhm @ 4A, 4.5V
VGS (th) (Max) @ Id	1V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	20nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	735pF @ 10V
Antriebsspannung (Max Rds On, Min Rds On)	1.8V, 4.5V
Vgs (Max)	±8V
Verpackung	Cut Tape (CT)
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)
Andere Namen	SI2374DS-T1-GE3CT

SI2374DS-T1-GE3 ist neu im Original, Suche SI2374DS-T1-GE3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI2374DS-T1-GE3 Electro-Films (EFI) / Vishay mit Garantie und Vertrauen. Anfrage SI2374DS-T1-GE3: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>SI2377DS-T1-GE3 V SI2377DS-T1-GE3 V</p>	 <p>SI2372DS-T1-E3 VISHAY SI2372DS-T1-E3 VISHAY</p>	 <p>SI2377 AOS SI2377 AOS</p>	 <p>SI2377DS-T1-E3 AOS AOS SOT-23</p>
 <p>SI2372DS-T1-GE3 Vishay / Siliconix MOSFET N-CHAN 30V SOT23</p>	 <p>SI2372DS-T1-GE3 Electro-Films (EFI) / Vishay MOSFET N-CHAN 30V SOT23</p>	 <p>SI2374DS-T1-GE3 Vishay / Siliconix MOSFET N-CHAN 20V SOT23</p>	 <p>SI2377EDS-T1-E3 VISHAY SI2377EDS-T1-E3 VISHAY</p>

heiße Teile

Mehr

⊛ SI2347DS-T1-GE3	↔ SI2347DS-T1-GE3	⇒ SI2351DS-T1-E3	D SI2351DS-T1-E3	↔ SI2351DS-T1-GE3
⊣ SI2351DS-T1-GE3	⊛ SI2356DS-T1-GE3	D SI2356DS-T1-GE3	⇒ SI2365EDS	↔ SI2365EDS-T1-GE3
⊛ SI2365EDS-T1-GE3	⊣ SI2366DS-T1-E3	⊛ SI2366DS-T1-GE	↔ SI2366DS-T1-GE3	↔ SI2366DS-T1-GE3
D SI2367DS-T1-E3	⊛ SI2367DS-T1-GE3	⊣ SI2367DS-T1-GE3	⊛ SI2369DS-T1-GE3	↔ SI2369DS-T1-GE3
⇒ SI2371EDS-T1-GE3	↔ SI2371EDS-T1-GE3	⊛ SI2372DS-T1-E3	⊣ SI2372DS-T1-GE3	↔ SI2372DS-T1-GE3
↔ SI2374DS-T1-GE3	⇒ SI2377DS-T1-GE3	D SI2377EDS	⊛ SI2377EDS-T1-E3	⊣ SI2377EDS-T1-GE3
⊛ SI2377EDS-T1-GE3	D SI2392ADS-T1-E3	⇒ SI2392ADS-T1-GE3	↔ SI2392ADS-T1-GE3	↔ SI2392DS-T1-GE3
⊣ SI2392DS-T1-GE3	⊛ SI2399CDS-T1-GE3	↔ SI2399DS-T1-GE3	⇒ SI2399DS-T1-GE3	↔ SI2400-B5
⊛ SI2400-FS	⊣ SI2400-FSR	⊛ SI2400-KS	D SI2400-KSR	↔ SI2401-FS
↔ SI2401-FSR	⊛ SI2401-FSR.	⊣ SI2401-KS	⊛ SI2403-FTR	↔ SI2404-C-FSR

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